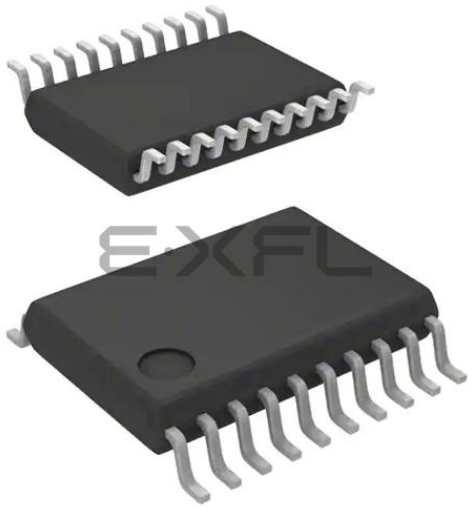
Renesas Electronics America Inc - R5F211A2SP#U0 Datasheet



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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I²C, SIO, SSU, UART/USART
Peripherals	LED, POR, Voltage Detect, WDT
Number of I/O	13
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 4x10b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	20-LSSOP
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f211a2sp-u0

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1.2 Performance Overview

Table 1.1 outlines the Functions and Specifications for R8C/1A Group and Table 1.2 outlines the Functions and Specifications for R8C/1B Group.

Table 1.1 Functions and Specifications for R8C/1A Group

Item		Specification
CPU	Number of fundamental instructions	89 instructions
	Minimum instruction execution time	50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) 100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V)
	Operating mode	Single-chip
	Address space	1 Mbyte
	Memory capacity	See **Table 1.3 Product Information for R8C/1A Group**
Peripheral Functions	Ports	I/O ports: 13 pins (including LED drive port) Input port: 3 pins
	LED drive ports	I/O ports: 4 pins
	Timers	Timer X: 8 bits × 1 channel, timer Z: 8 bits × 1 channel (Each timer equipped with 8-bit prescaler) Timer C: 16 bits × 1 channel (Input capture and output compare circuits)
	Serial interfaces	1 channel Clock synchronous serial I/O, UART 1 channel UART
	Clock synchronous serial interface	1 channel I^2C bus Interface(1) Clock synchronous serial I/O with chip select (SSU)
	A/D converter	10-bit A/D converter: 1 circuit, 4 channels
	Watchdog timer	15 bits × 1 channel (with prescaler) Reset start selectable, count source protection mode
	Interrupts	Internal: 11 sources, External: 4 sources, Software: 4 sources, Priority levels: 7 levels
	Clock generation circuits	2 circuits • Main clock oscillation circuit (with on-chip feedback resistor) • On-chip oscillator (high speed, low speed) High-speed on-chip oscillator has a frequency adjustment function
	Oscillation stop detection function	Main clock oscillation stop detection function
	Voltage detection circuit	On-chip
	Power-on reset circuit	On-chip
Electric Characteristics	Supply voltage	VCC = 3.0 to 5.5 V (f(XIN) = 20 MHz) VCC = 2.7 to 5.5 V (f(XIN) = 10 MHz)
	Current consumption	Typ. 9 mA (VCC = 5.0 V, f(XIN) = 20 MHz, A/D converter stopped) Typ. 5 mA (VCC = 3.0 V, f(XIN) = 10 MHz, A/D converter stopped) Typ. 35 μA (VCC = 3.0 V, wait mode, peripheral clock off) Typ. 0.7 μA (VCC = 3.0 V, stop mode)
Flash Memory	Programming and erasure voltage	VCC = 2.7 to 5.5 V
	Programming and erasure endurance	100 times
Operating Ambient Temperature		-20 to 85°C
		-40 to 85°C (D version)
		-20 to 105°C (Y version) (2)
Package		20-pin molded-plastic LSSOP
		20-pin molded-plastic SDIP
		28-pin molded-plastic HWQFN

NOTE:
1. I^2C bus is a trademark of Koninklijke Philips Electronics N. V.
2. Please contact Renesas Technology sales offices for the Y version.

Table 1.2 Functions and Specifications for R8C/1B Group

Item		Specification
CPU	Number of fundamental instructions	89 instructions
	Minimum instruction execution time	50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) 100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V)
	Operating mode	Single-chip
	Address space	1 Mbyte
	Memory capacity	See **Table 1.4 Product Information for R8C/1B Group**
Peripheral Functions	Ports	I/O ports: 13 pins (including LED drive port) Input port: 3 pins
	LED drive ports	I/O ports: 4 pins
	Timers	Timer X: 8 bits × 1 channel, timer Z: 8 bits × 1 channel (Each timer equipped with 8-bit prescaler) Timer C: 16 bits × 1 channel (Input capture and output compare circuits)
	Serial interfaces	1 channel Clock synchronous serial I/O, UART 1 channel UART
	Clock synchronous serial interface	1 channel I²C bus Interface(1) Clock synchronous serial I/O with chip select (SSU)
	A/D converter	10-bit A/D converter: 1 circuit, 4 channels
	Watchdog timer	15 bits × 1 channel (with prescaler) Reset start selectable, count source protection mode
	Interrupts	Internal: 11 sources, External: 4 sources, Software: 4 sources, Priority levels: 7 levels
	Clock generation circuits	2 circuits • Main clock generation circuit (with on-chip feedback resistor) • On-chip oscillator (high speed, low speed) High-speed on-chip oscillator has a frequency adjustment function
	Oscillation stop detection function	Main clock oscillation stop detection function
	Voltage detection circuit	On-chip
	Power on reset circuit	On-chip
Electric Characteristics	Supply voltage	VCC = 3.0 to 5.5 V (f(XIN) = 20 MHz) VCC = 2.7 to 5.5 V (f(XIN) = 10 MHz)
	Current consumption	Typ. 9 mA (VCC = 5.0 V, f(XIN) = 20 MHz, A/D converter stopped) Typ. 5 mA (VCC = 3.0 V, f(XIN) = 10 MHz, A/D converter stopped) Typ. 35 μA (VCC = 3.0 V, wait mode, peripheral clock off) Typ. 0.7 μA (VCC = 3.0 V, stop mode)
Flash Memory	Programming and erasure voltage	VCC = 2.7 to 5.5 V
	Programming and erasure endurance	10,000 times (data flash) 1,000 times (program ROM)
Operating Ambient Temperature		-20 to 85°C -40 to 85°C (D version) -20 to 105°C (Y version) (2)
Package		20-pin molded-plastic LSSOP 20-pin molded-plastic SDIP 28-pin molded-plastic HWQFN

NOTE:
1. I²C bus is a trademark of Koninklijke Philips Electronics N. V.
2. Please contact Renesas Technology sales offices for the Y version.

1.3 Block Diagram

Figure 1.1 shows a Block Diagram.

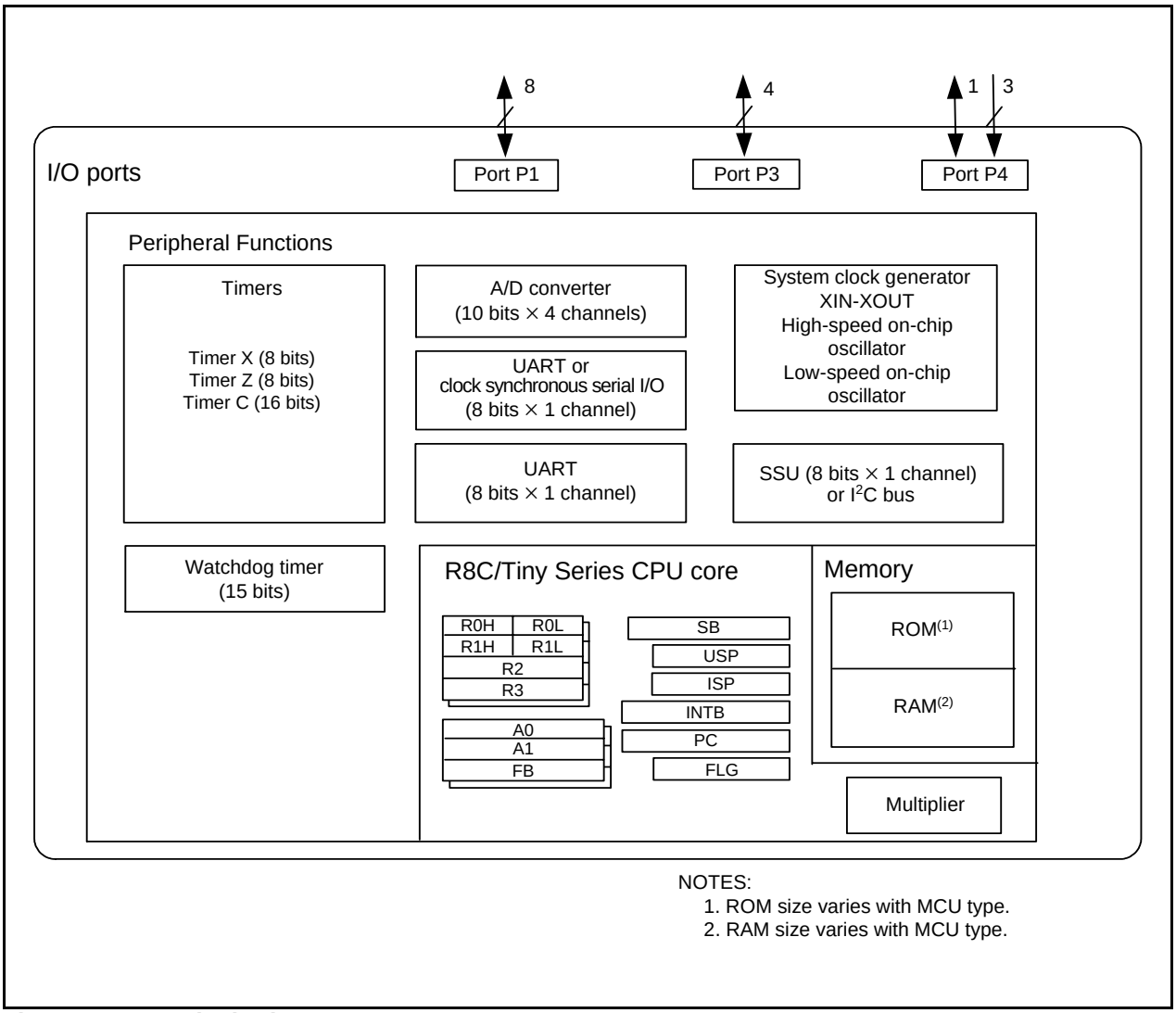


Figure 1.1 Block Diagram

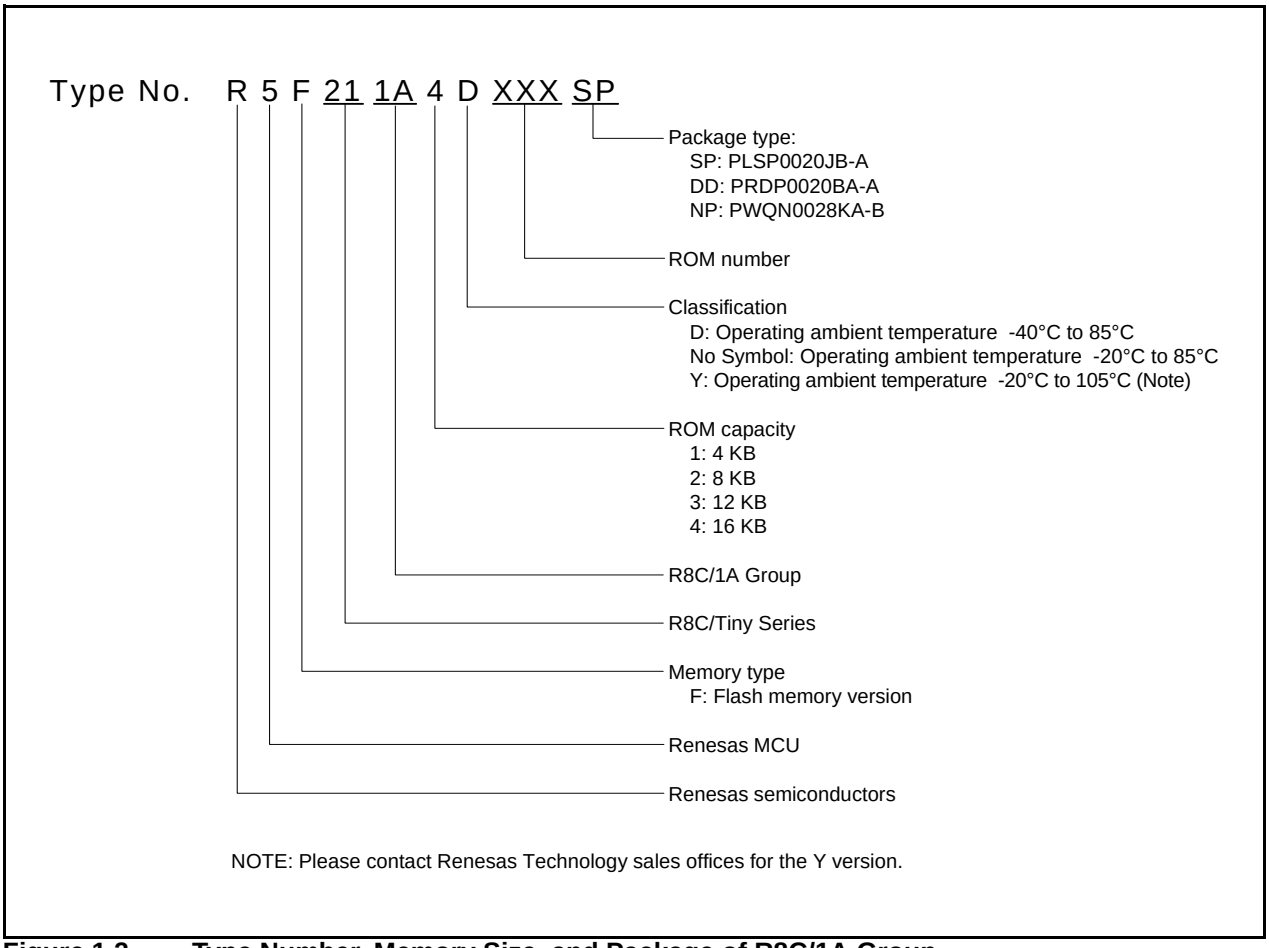


Figure 1.2 Type Number, Memory Size, and Package of R8C/1A Group

Table 1.4 Product Information for R8C/1B Group Current of October 2006

Type No.	ROM Capacity		RAM Capacity	Package Type	Remarks
	Program ROM	Data Flash			
R5F211B1SP	4 Kbytes	1 Kbyte × 2	384 bytes	PLSP0020JB-A	
R5F211B2SP	8 Kbytes	1 Kbyte × 2	512 bytes	PLSP0020JB-A	
R5F211B3SP	12 Kbytes	1 Kbyte × 2	768 bytes	PLSP0020JB-A	
R5F211B4SP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLSP0020JB-A	
R5F211B1DSP	4 Kbytes	1 Kbyte × 2	384 bytes	PLSP0020JB-A	D version
R5F211B2DSP	8 Kbytes	1 Kbyte × 2	512 bytes	PLSP0020JB-A	
R5F211B3DSP	12 Kbytes	1 Kbyte × 2	768 bytes	PLSP0020JB-A	
R5F211B4DSP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLSP0020JB-A	
R5F211B1DD	4 Kbytes	1 Kbyte × 2	384 bytes	PRDP0020BA-A	
R5F211B2DD	8 Kbytes	1 Kbyte × 2	512 bytes	PRDP0020BA-A	
R5F211B3DD	12 Kbytes	1 Kbyte × 2	768 bytes	PRDP0020BA-A	
R5F211B4DD	16 Kbytes	1 Kbyte × 2	1 Kbyte	PRDP0020BA-A	
R5F211B2NP	8 Kbytes	1 Kbyte × 2	512 bytes	PWQN0028KA-B	
R5F211B3NP	12 Kbytes	1 Kbyte × 2	768 bytes	PWQN0028KA-B	
R5F211B4NP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PWQN0028KA-B	
R5F211B1XXXSP	4 Kbytes	1 Kbyte × 2	384 bytes	PLSP0020JB-A	Factory programming product (1)
R5F211B2XXXSP	8 Kbytes	1 Kbyte × 2	512 bytes	PLSP0020JB-A	
R5F211B3XXXSP	12 Kbytes	1 Kbyte × 2	768 bytes	PLSP0020JB-A	
R5F211B4XXXSP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLSP0020JB-A	
R5F211B1DXXXSP	4 Kbytes	1 Kbyte × 2	384 bytes	PLSP0020JB-A	D version
R5F211B2DXXXSP	8 Kbytes	1 Kbyte × 2	512 bytes	PLSP0020JB-A	
R5F211B3DXXXSP	12 Kbytes	1 Kbyte × 2	768 bytes	PLSP0020JB-A	
R5F211B4DXXXSP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLSP0020JB-A	
R5F211B1XXXDD	4 Kbytes	1 Kbyte × 2	384 bytes	PRDP0020BA-A	Factory programming product (1)
R5F211B2XXXDD	8 Kbytes	1 Kbyte × 2	512 bytes	PRDP0020BA-A	
R5F211B3XXXDD	12 Kbytes	1 Kbyte × 2	768 bytes	PRDP0020BA-A	
R5F211B4XXXDD	16 Kbytes	1 Kbyte × 2	1 Kbyte	PRDP0020BA-A	
R5F211B2XXXNP	8 Kbytes	1 Kbyte × 2	512 bytes	PWQN0028KA-B	
R5F211B3XXXNP	12 Kbytes	1 Kbyte × 2	768 bytes	PWQN0028KA-B	
R5F211B4XXXNP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PWQN0028KA-B	

NOTE:
1. The user ROM is programmed before shipment.

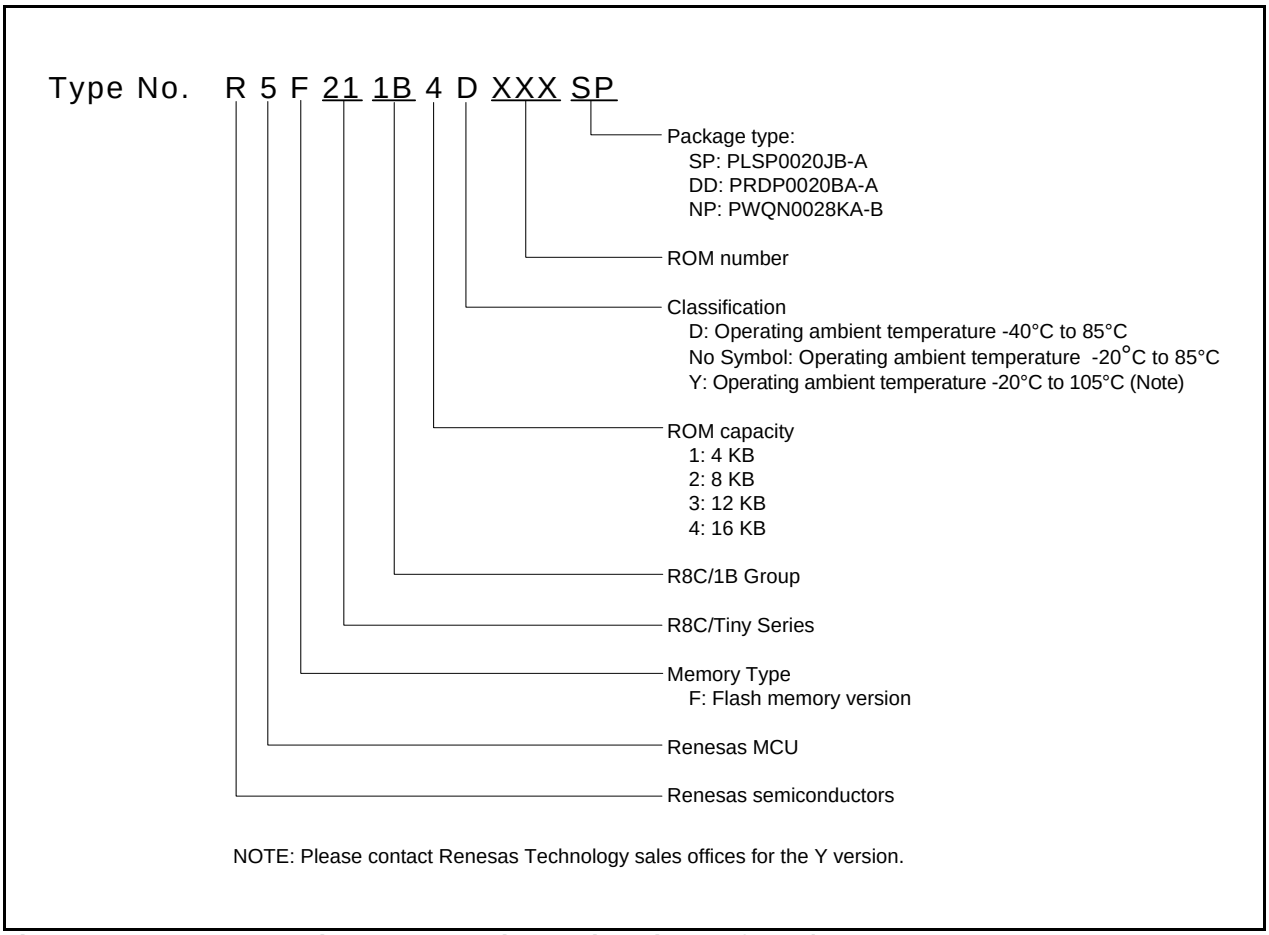


Figure 1.3 Type Number, Memory Size, and Package of R8C/1B Group

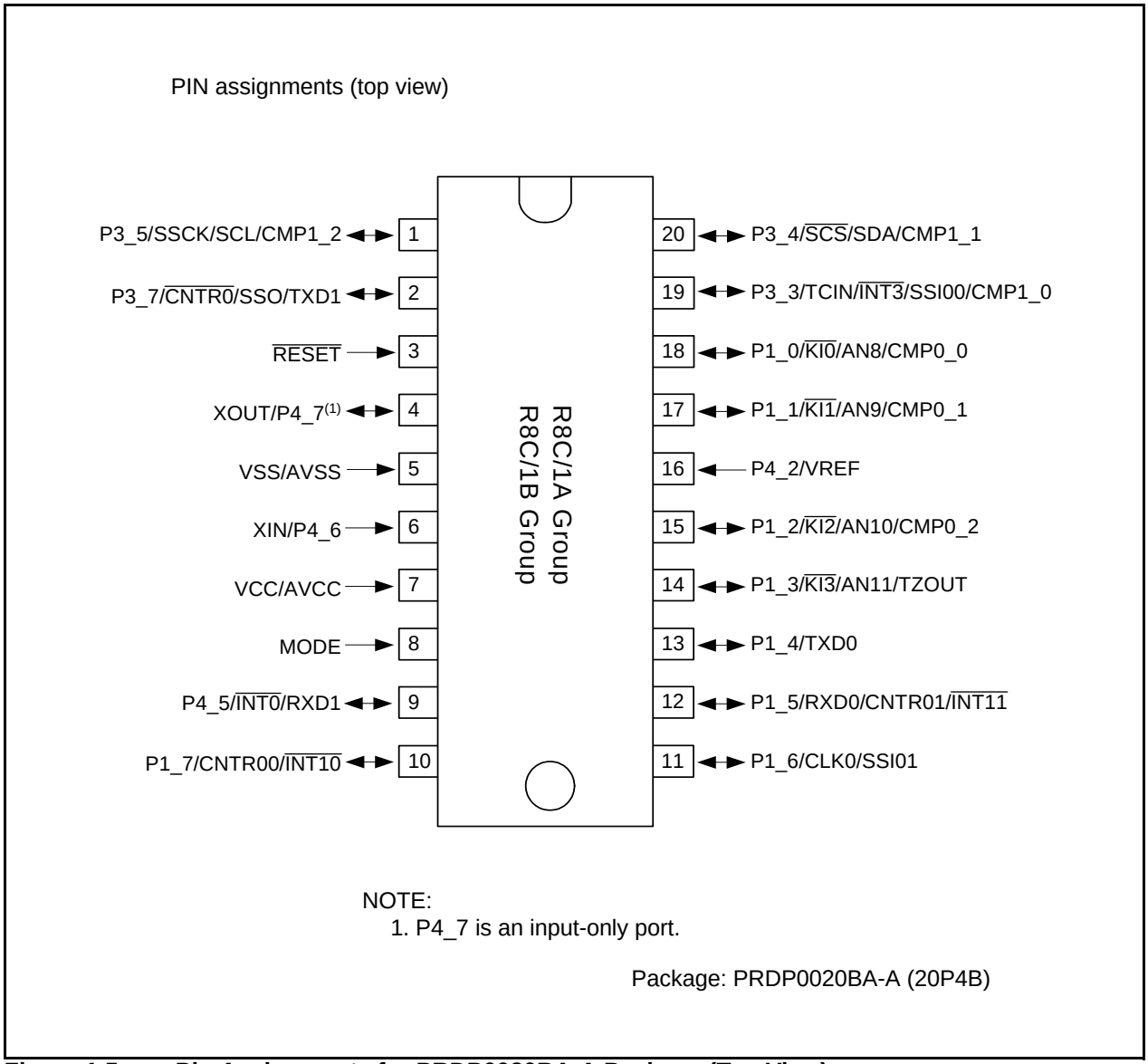
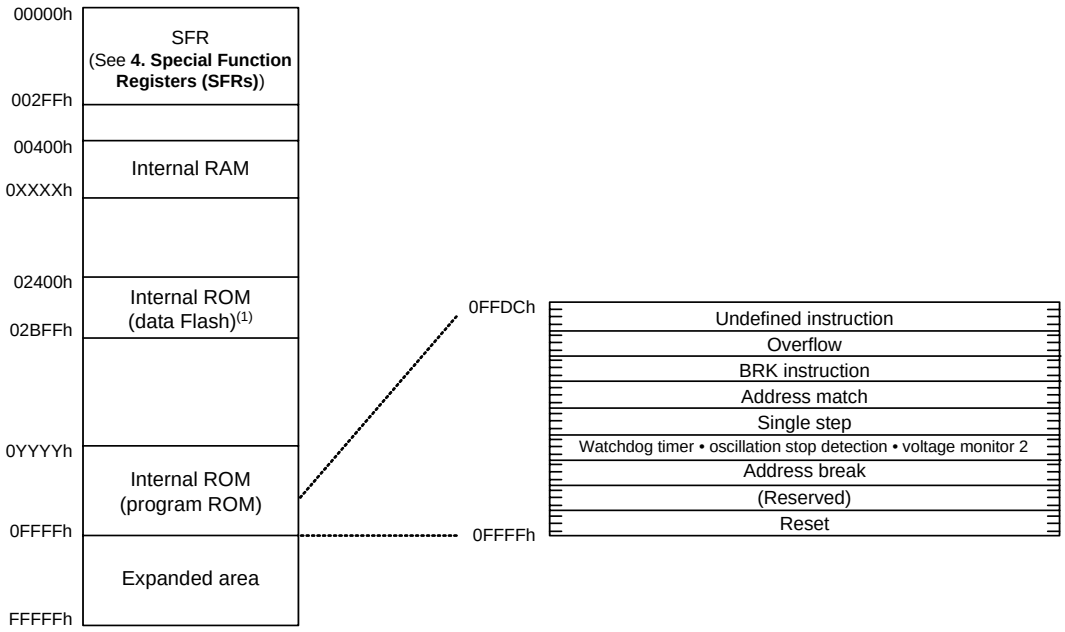


Figure 1.5 Pin Assignments for PRDP0020BA-A Package (Top View)

3.2 R8C/1B Group

Figure 3.2 is a Memory Map of R8C/1B Group. The R8C/1B Group has 1 Mbyte of address space from addresses 00000h to FFFFFh.
The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.
The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.
The internal ROM (data flash) is allocated addresses 02400h to 02BFFh.
The internal RAM is allocated higher addresses beginning with address 00400h. For example, a 1-Kbyte internal RAM area is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.
Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.



NOTES:
1. Data flash block A (1 Kbyte) and B (1 Kbyte) are shown.
2. The blank regions are reserved. Do not access locations in these regions.

Part Number	Internal ROM		Internal RAM	
	Size	Address 0YYYYh	Size	Address 0XXXXh
R5F211B4SP, R5F211B4DSP, R5F211B4DD, R5F211B4NP, R5F211B4XXXSP, R5F211B4DXXXSP, R5F211B4XXXDD, R5F211B4XXXNP	16 Kbytes	0C000h	1 Kbyte	007FFh
R5F211B3SP, R5F211B3DSP, R5F211B3DD, R5F211B3NP, R5F211B3XXXSP, R5F211B3DXXXSP, R5F211B3XXXDD, R5F211B3XXXNP	12 Kbytes	0D000h	768 bytes	006FFh
R5F211B2SP, R5F211B2DSP, R5F211B2DD, R5F211B2NP, R5F211B2XXXSP, R5F211B2DXXXSP, R5F211B2XXXDD, R5F211B2XXXNP	8 Kbytes	0E000h	512 bytes	005FFh
R5F211B1SP, R5F211B1DSP, R5F211B1DD, R5F211B1XXXSP, R5F211B1DXXXSP, R5F211B1XXXDD	4 Kbytes	0F000h	384 bytes	0057Fh

Figure 3.2 Memory Map of R8C/1B Group

Table 4.3 SFR Information (3)(1)

Address	Register	Symbol	After reset
0080h	Timer Z Mode Register	TZMR	00h
0081h			
0082h			
0083h			
0084h	Timer Z Waveform Output Control Register	PUM	00h
0085h	Prescaler Z Register	PREZ	FFh
0086h	Timer Z Secondary Register	TZSC	FFh
0087h	Timer Z Primary Register	TZPR	FFh
0088h			
0089h			
008Ah	Timer Z Output Control Register	TZOC	00h
008Bh	Timer X Mode Register	TXMR	00h
008Ch	Prescaler X Register	PREX	FFh
008Dh	Timer X Register	TX	FFh
008Eh	Timer Count Source Setting Register	TCSS	00h
008Fh			
0090h	Timer C Register	TC	00h
0091h			00h
0092h			
0093h			
0094h			
0095h			
0096h	External Input Enable Register	INTEN	00h
0097h			
0098h	Key Input Enable Register	KIEN	00h
0099h			
009Ah	Timer C Control Register 0	TCC0	00h
009Bh	Timer C Control Register 1	TCC1	00h
009Ch	Capture, Compare 0 Register	TM0	0000h(2)
009Dh			FFFFh(3)
009Eh	Compare 1 Register	TM1	FFh
009Fh			FFh
00A0h	UART0 Transmit/Receive Mode Register	U0MR	00h
00A1h	UART0 Bit Rate Generator	U0BRG	XXh
00A2h	UART0 Transmit Buffer Register	U0TB	XXh
00A3h			XXh
00A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
00A5h	UART0 Transmit/Receive Control Register 1	U0C1	00000010b
00A6h	UART0 Receive Buffer Register	U0RB	XXh
00A7h			XXh
00A8h	UART1 Transmit/Receive Mode Register	U1MR	00h
00A9h	UART1 Bit Rate Generator	U1BRG	XXh
00AAh	UART1 Transmit Buffer Register	U1TB	XXh
00ABh			XXh
00ACh	UART1 Transmit/Receive Control Register 0	U1C0	00001000b
00ADh	UART1 Transmit/Receive Control Register 1	U1C1	00000010b
00AEh	UART1 Receive Buffer Register	U1RB	XXh
00AFh			XXh
00B0h	UART Transmit/Receive Control Register 2	UCON	00h
00B1h			
00B2h			
00B3h			
00B4h			
00B5h			
00B6h			
00B7h			
00B8h	SS Control Register H / IIC bus Control Register 1(4)	SSCRH / ICCR1	00h
00B9h	SS Control Register L / IIC bus Control Register 2(4)	SSCRL / ICCR2	01111101b
00BAh	SS Mode Register / IIC bus Mode Register(4)	SSMR / ICMR	00011000b
00BBh	SS Enable Register / IIC bus Interrupt Enable Register(4)	SSER / ICIER	00h
00BCh	SS Status Register / IIC bus Status Register(4)	SSSR / ICSR	00h / 0000X000b
00BDh	SS Mode Register 2 / Slave Address Register(4)	SSMR2 / SAR	00h
00BEh	SS Transmit Data Register / IIC bus Transmit Data Register(4)	SSTDR / ICDRT	FFh
00BFh	SS Receive Data Register / IIC bus Receive Data Register(4)	SSRDR / ICDRR	FFh

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.
2. In input capture mode.
3. In output compare mode.
4. Selected by the IICSEL bit in the PMR register.

5. Electrical Characteristics

Please contact Renesas Technology sales offices for the electrical characteristics in the Y version (Topr = -20°C to 105°C).

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
V_{CC}	Supply voltage	V_{CC} = AV_{CC}	-0.3 to 6.5	V
AV_{CC}	Analog supply voltage	V_{CC} = AV_{CC}	-0.3 to 6.5	V
V_I	Input voltage		-0.3 to V_{CC}+0.3	V
V_O	Output voltage		-0.3 to V_{CC}+0.3	V
P_d	Power dissipation	T_{opr} = 25°C	300	mW
T_{opr}	Operating ambient temperature		-20 to 85 / -40 to 85 (D version)	°C
T_{stg}	Storage temperature		-65 to 150	°C

Table 5.2 Recommended Operating Conditions

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
V_{CC}	Supply voltage			2.7	–	5.5	V
AV_{CC}	Analog supply voltage			–	V_{CC}	–	V
V_{SS}	Supply voltage			–	0	–	V
AV_{SS}	Analog supply voltage			–	0	–	V
V_{IH}	Input “H” voltage			0.8V_{CC}	–	V_{CC}	V
V_{IL}	Input “L” voltage			0	–	0.2V_{CC}	V
$I_{OH(sum)}$	Peak sum output “H” current	Sum of all pins $I_{OH\ (peak)}$		–	–	-60	mA
$I_{OH(peak)}$	Peak output “H” current			–	–	-10	mA
$I_{OH(avg)}$	Average output “H” current			–	–	-5	mA
$I_{OL(sum)}$	Peak sum output “L” currents	Sum of all pins $I_{OL\ (peak)}$		–	–	60	mA
$I_{OL(peak)}$	Peak output “L” currents	Except P1_0 to P1_3		–	–	10	mA
		P1_0 to P1_3	Drive capacity HIGH	–	–	30	mA
			Drive capacity LOW	–	–	10	mA
$I_{OL(avg)}$	Average output “L” current	Except P1_0 to P1_3		–	–	5	mA
		P1_0 to P1_3	Drive capacity HIGH	–	–	15	mA
			Drive capacity LOW	–	–	5	mA
$f_{(XIN)}$	Main clock input oscillation frequency		3.0 V ≤ V_{CC} ≤ 5.5 V	0	–	20	MHz
			2.7 V ≤ V_{CC} < 3.0 V	0	–	10	MHz
–	System clock	OCD2 = 0 Main clock selected	3.0 V ≤ V_{CC} ≤ 5.5 V	0	–	20	MHz
			2.7 V ≤ V_{CC} < 3.0 V	0	–	10	MHz
		OCD2 = 1 On-chip oscillator clock selected	HRA01 = 0 Low-speed on-chip oscillator clock selected	–	125	–	kHz
			HRA01 = 1 High-speed on-chip oscillator clock selected	–	8	–	MHz

NOTES:
1. V_{CC} = 2.7 to 5.5 V at T_{opr} = -20 to 85 °C / -40 to 85 °C, unless otherwise specified.
2. Typical values when average output current is 100 ms.

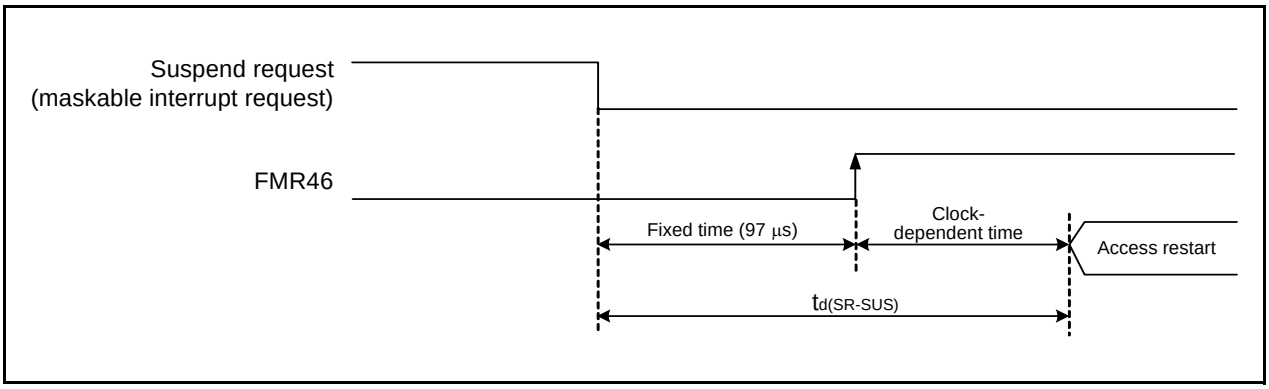


Figure 5.2 Transition Time to Suspend

Table 5.6 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V_{det1}	Voltage detection level(3)		2.70	2.85	3.00	V
–	Voltage detection circuit self power consumption	VCA26 = 1, V_{CC} = 5.0 V	–	600	–	nA
$t_{d(E-A)}$	Waiting time until voltage detection circuit operation starts(2)		–	–	100	µs
Vccmin	MCU operating voltage minimum value		2.7	–	–	V

NOTES:
1. The measurement condition is V_{CC} = 2.7 V to 5.5 V and T_{opr} = -40°C to 85 °C.
2. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.
3. Ensure that $V_{det2} > V_{det1}$.

Table 5.7 Voltage Detection 2 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V_{det2}	Voltage detection level(4)		3.00	3.30	3.60	V
–	Voltage monitor 2 interrupt request generation time(2)		–	40	–	µs
–	Voltage detection circuit self power consumption	VCA27 = 1, V_{CC} = 5.0 V	–	600	–	nA
$t_{d(E-A)}$	Waiting time until voltage detection circuit operation starts(3)		–	–	100	µs

NOTES:
1. The measurement condition is V_{CC} = 2.7 V to 5.5 V and T_{opr} = -40°C to 85 °C.
2. Time until the voltage monitor 2 interrupt request is generated after the voltage passes V_{det2}.
3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.
4. Ensure that $V_{det2} > V_{det1}$.

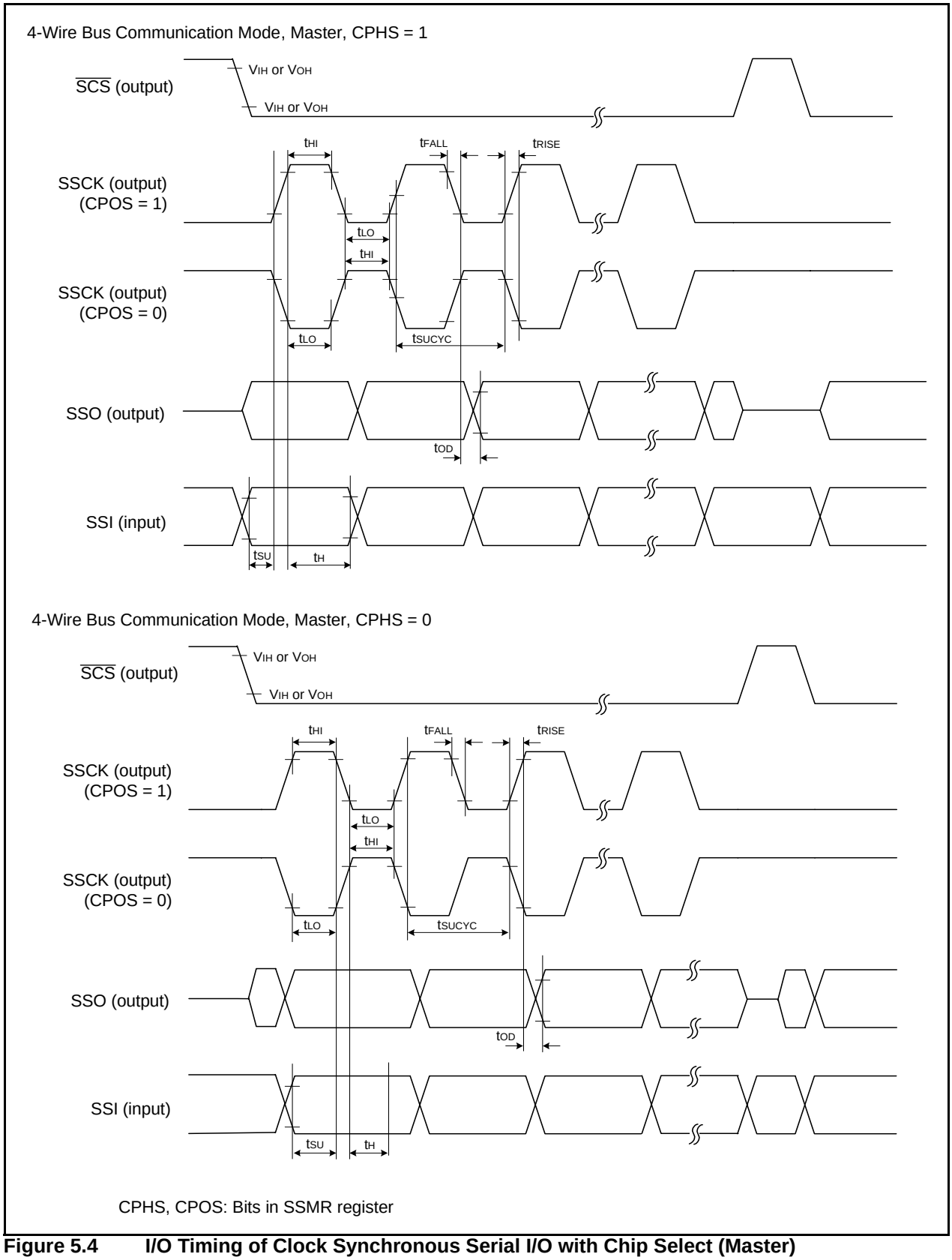


Figure 5.4 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Master)

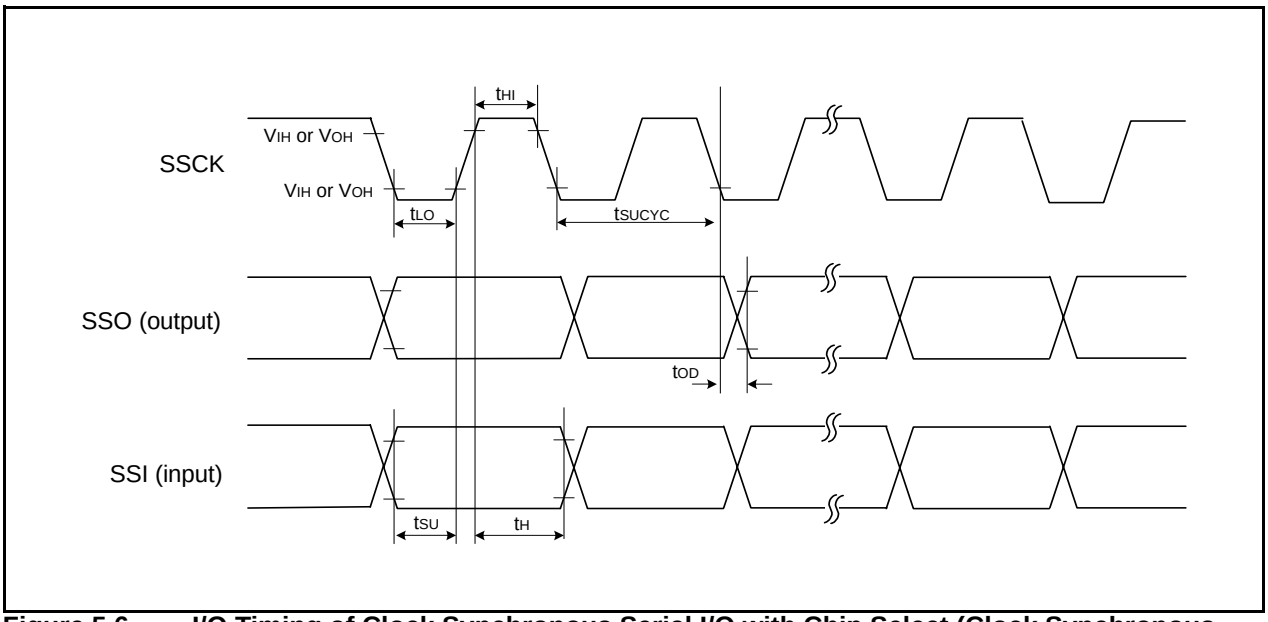
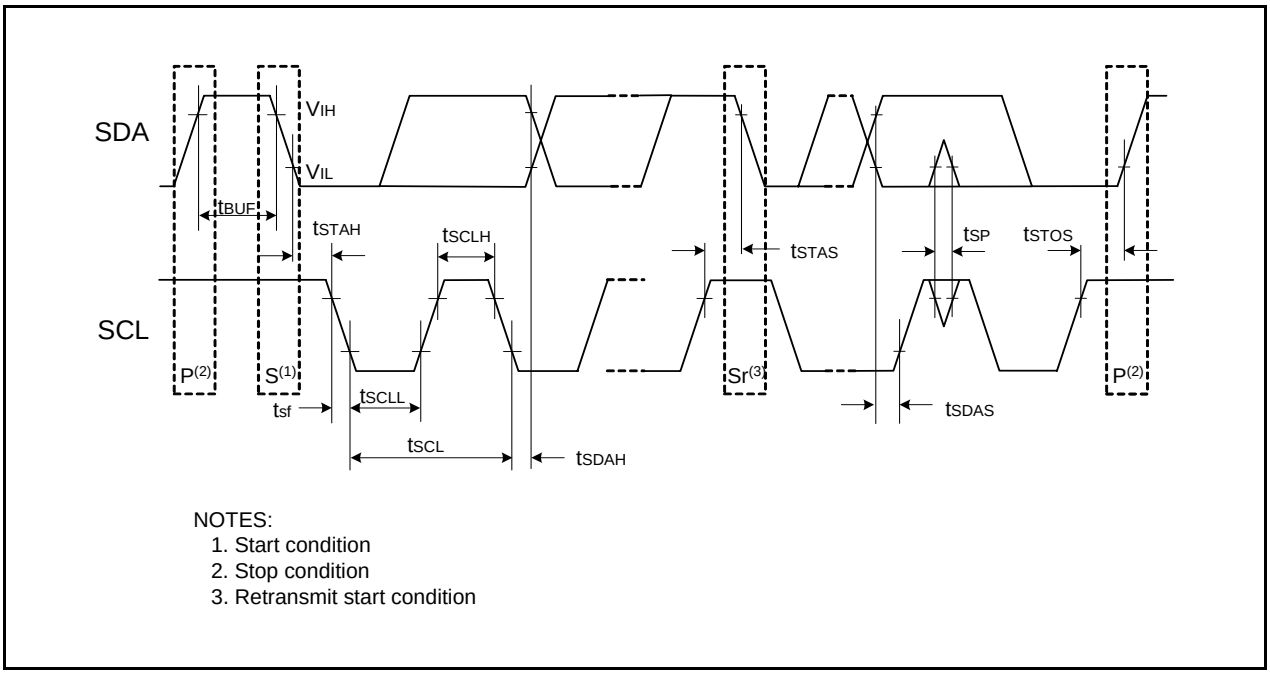


Figure 5.6 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Clock Synchronous Communication Mode)

Table 5.13 Timing Requirements of I²C bus Interface (1)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t_{SCL}	SCL input cycle time		$12t_{CYC}+600^{(2)}$	–	–	ns
t_{SCLH}	SCL input “H” width		$3t_{CYC}+300^{(2)}$	–	–	ns
t_{SCLL}	SCL input “L” width		$5t_{CYC}+300^{(2)}$	–	–	ns
t_{sf}	SCL, SDA input fall time		–	–	300	ns
t_{SP}	SCL, SDA input spike pulse rejection time		–	–	$1t_{CYC}^{(2)}$	ns
t_{BUF}	SDA input bus-free time		$5t_{CYC}^{(2)}$	–	–	ns
t_{STAH}	Start condition input hold time		$3t_{CYC}^{(2)}$	–	–	ns
t_{STAS}	Retransmit start condition input setup time		$3t_{CYC}^{(2)}$	–	–	ns
t_{STOS}	Stop condition input setup time		$3t_{CYC}^{(2)}$	–	–	ns
t_{SDAS}	Data input setup time		$1t_{CYC}+20^{(2)}$	–	–	ns
t_{SDAH}	Data input hold time		0	–	–	ns

NOTES:
1. V_{CC} = 2.7 to 5.5 V, V_{SS} = 0 V and Ta = -20 to 85 °C / -40 to 85 °C, unless otherwise specified.
2. $1t_{CYC}$ = 1/f1(s)



NOTES:
1. Start condition
2. Stop condition
3. Retransmit start condition

Figure 5.7 I/O Timing of I²C bus Interface

Timing Requirements
(Unless otherwise specified: Vcc = 5 V, Vss = 0 V at Ta = 25 °C) [Vcc = 5 V]

Table 5.16 XIN Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(XIN)}$	XIN input cycle time	50	–	ns
$t_{WH(XIN)}$	XIN input “H” width	25	–	ns
$t_{WL(XIN)}$	XIN input “L” width	25	–	ns

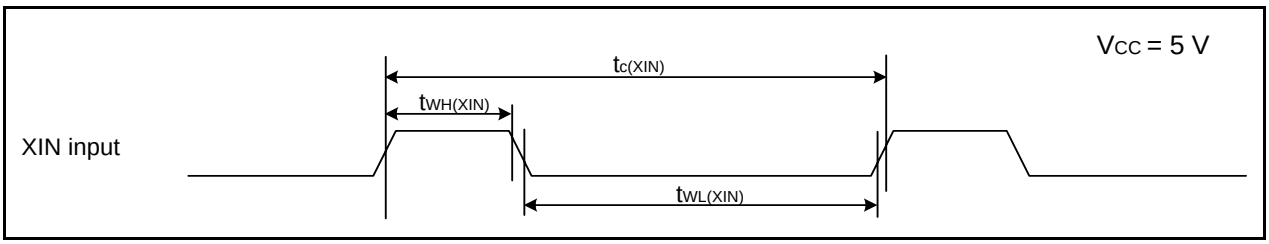


Figure 5.8 XIN Input Timing Diagram when Vcc = 5 V

Table 5.17 CNTR0 Input, CNTR1 Input, $\overline{\text{INT1}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CNTR0)}$	CNTR0 input cycle time	100	–	ns
$t_{WH(CNTR0)}$	CNTR0 input “H” width	40	–	ns
$t_{WL(CNTR0)}$	CNTR0 input “L” width	40	–	ns

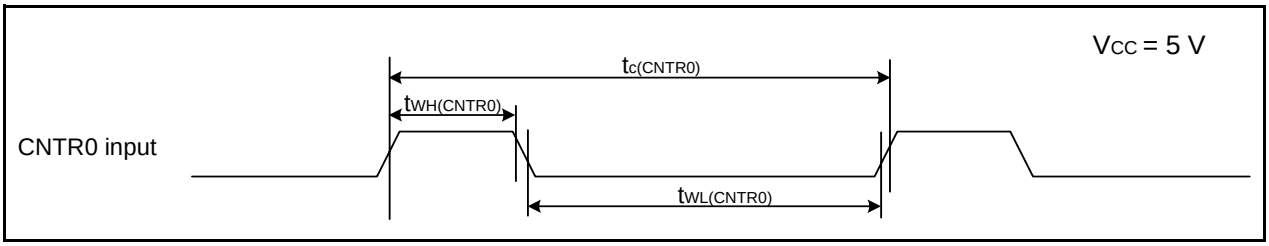


Figure 5.9 CNTR0 Input, CNTR1 Input, $\overline{\text{INT1}}$ Input Timing Diagram when Vcc = 5 V

Table 5.18 TCIN Input, $\overline{\text{INT3}}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TCIN)}$	TCIN input cycle time	400(1)	–	ns
$t_{WH(TCIN)}$	TCIN input “H” width	200(2)	–	ns
$t_{WL(TCIN)}$	TCIN input “L” width	200(2)	–	ns

NOTES:
1. When using timer C input capture mode, adjust the cycle time to (1/timer C count source frequency x 3) or above.
2. When using timer C input capture mode, adjust the pulse width to (1/timer C count source frequency x 1.5) or above.

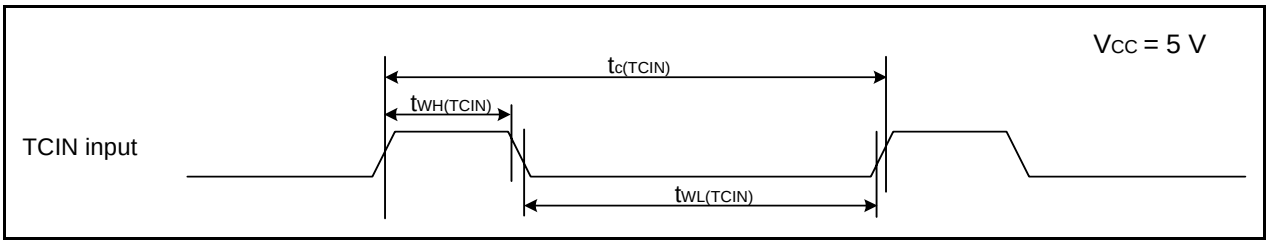
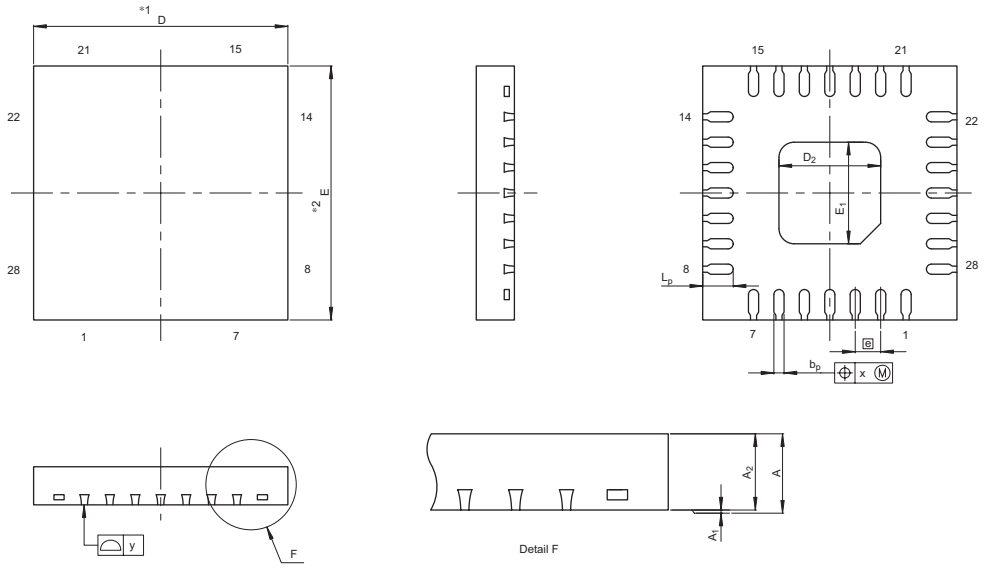


Figure 5.10 TCIN Input, $\overline{\text{INT3}}$ Input Timing Diagram when Vcc = 5 V

Table 5.22 Electrical Characteristics (4) [Vcc = 3 V] (Topr = -40 to 85 °C, unless otherwise specified.)

Symbol	Parameter	Condition		Standard			Unit
				Min.	Typ.	Max.	
I_{CC}	Power supply current (V_{CC} = 2.7 to 3.3 V) Single-chip mode, output pins are open, other pins are V_{SS}, A/D converter is stopped	High-speed mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	8	13	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	7	12	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	5	–	mA
		Medium-speed mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	3	–	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2.5	–	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.6	–	mA
		High-speed on-chip oscillator mode	Main clock off High-speed on-chip oscillator on = 8 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	3.5	7.5	mA
			Main clock off High-speed on-chip oscillator on = 8 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.5	–	mA
		Low-speed on-chip oscillator mode	Main clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8 FMR47 = 1	–	100	280	µA
		Wait mode	Main clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = 0	–	37	74	µA
		Wait mode	Main clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = 0	–	35	70	µA
		Stop mode	Main clock off, Topr = 25 °C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = 0	–	0.7	3.0	µA

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-HWQFN28-5x5-0.50	PWQN0028KA-B	28PJW-B	0.05g



NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	4.9	5.0	5.1
E	4.9	5.0	5.1
A_2	—	0.75	—
A	—	—	0.8
A_1	0	0	0.05
b_p	0.15	0.2	0.25
e	—	0.5	—
L_p	0.5	0.6	0.7
x	—	—	0.05
y	—	—	0.05
D_2	—	2.0	—
E_1	—	2.0	—

REVISION HISTORY	R8C/1A Group, R8C/1B Group Datasheet

Rev.	Date	Description	
		Page	Summary
0.10	Feb 18, 2005	–	First Edition issued
0.20	Jun 01, 2005	2, 3	Tables 1.1, 1.2: Item name changed
		9	Table 1.5: Timer C's Pin name revised, Reference Voltage Input Description revised
0.30	Jul 04, 2005	16	Table 4.1 the value after reset revised; 0009h address "XXXXXX00b" → "00h", 000Ah address "00XXX000b" → "00h", 001Eh address "XXXXX000b" → "00h".
		17	Table 4.2 004Fh address; "SSU/IIC Interrupt Control Register, SSUAIC/IIC2AIC, XXXXX000b" added
		18	Table 4.3 the value after reset revised; 00BCh address "00h" → "00h / 0000X000b"
		20 to 39	5. Electrical Characteristics added
1.00	Sep 01, 2005	all pages	"Under development" deleted
		3	Table 1.2 Performance Outline of the R8C/1B Group; Flash Memory: (Data area) → (Data flash) (Program area) → (Program ROM) revised
		4	Figure 1.1 Block Diagram; "Peripheral Function" added, "System Clock Generation" → "System Clock Generator" revised
		5	Table 1.3 Product Information of R8C/1A Group; "(D)" and "(D): Under development" deleted
		6	Table 1.4 Product Information of R8C/1B Group; "(D)" and "(D): Under development" deleted ROM capacity: (Program area) → (Program ROM), (Data area) → (Data flash) revised
		9	Table 1.5 Pin Description; Power Supply Input: "VCC/AVCC" → "VCC", "VSS/AVSS" → "VSS" revised Analog Power Supply Input: added
		11	Figure 2.1 CPU Register; "Reserved Area" → "Reserved Bit" revised
		13	2.8.10 Reserved Area; "Reserved Area" → "Reserved Bit" revised
		15	3.2 R8C/1B Group, Figure 3.2 Memory Map of R8C/1B Group; "Data area" → "Data flash", "Program area" → "Program ROM" revised

REVISION HISTORY	R8C/1A Group, R8C/1B Group Datasheet

Rev.	Date	Description	
		Page	Summary
1.30	Oct 03, 2006	1	1.1 “portable equipment” added
		2, 3	Table 1.1, Table 1.2; Specification Interrupts: “Internal: 9 sources” → “Internal: 11 sources”
		24	Table 5.2; Parameter: System clock added
		45	Package Dimensions; PWQN0028KA-B revised
1.40	Dec 08, 2006	20	Table 4.1; 000Fh: After reset “000XXXXXb” → “00X11111b”
		24	Table 19.2; Parameter: OCD2 = 1 On-chip oscillator clock selected revised